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TABLE OF CONTENTS

SESSION A: PLENARY SESSION

The Early Days of GaAs ICs	1
<i>R.L. Van Tuyl</i>	
DARPA's Nitride Electronic NeXt Generation Technology Program	5
<i>J.D. Albrecht, T. Chang, A.S. Kane, M.J. Rosker</i>	
A Hybrid Optoelectronic Router and Enabling InP OEIC Technologies	9
<i>R. Urata, T. Nakahara, H. Takenouchi, T. Segawa, R. Takahashi</i>	
The DARPA COSMOS and ELASTx Programs: Towards Next Generation Linearized Microwave/Mm-Wave Transmitters	13
<i>S. Raman, T. Chang, I. Abdomerovic, C.L. Dohrman, C. Maxey, M.J. Rosker</i>	

SESSION B: HANDSET AND BASESTATION FRONT-ENDS

Reconfigurable RF Front-Ends for Cellular Receivers	17
<i>A. Mirzaei, H. Darabi</i>	
RF Front-End Tunability for LTE Handset Applications	21
<i>R. Whatley, T. Ranta, D. Kelly</i>	
Doherty Power Amplifiers using 2nd Generation HVHBT Technology for High Efficiency Basestation Applications	25
<i>C. Steinbeiser, P. Page, T. Landon, G. Burgin</i>	

SESSION C: GAN HEMT MODELING

AlGaIn/GaN HFET Models and the Prospects for Physics-Based Compact Models	29
<i>R.J. Trew</i>	
GaN Device Modeling with X-parameters	33
<i>J. Horn, D.E. Root, G. Simpson</i>	
A Scalable and Distributed Electro-thermal Model of AlGaIn/GaN HEMT Dedicated to Multi-fingers Transistors	37
<i>A. Xiong, C. Charbonniaud, E. Gatard, S. Dellier</i>	
A Verilog-A Large-Signal GaN HEMT Model for High Power Amplifier Design	41
<i>F. Kharabi, J.R.F. McMacken, J.M. Gering</i>	

SESSION D: HIGH SPEED DIGITAL CIRCUITS

A 204.8GHz Static Divide-by-8 Frequency Divider in 250nm InP HBT	45
<i>Z. Griffith, M. Urteaga, R. Pierson, P. Rowell, M. Rodwell, B. Brar</i>	
A 4 by 28.3 Gb/s SFI-S SerDes in 130 nm SiGe	49
<i>T. Krawczyk, T. Cooper, S. Steidl, P. Curran, M. Yamagata, S. Shang, T. Liu, J. Pulver, C. Duong, Z. Wang, D. Walworth, C. Hornbuckle, D. Rowe</i>	
A 40-Gb/s Multi-data-rate CMOS Transmitter and Receiver Chipset with SFI-5 Interface for Optical Transmission Systems	53
<i>H. Noguchi, T. Yamase, K. Hosoya, M. Okamoto, H. Yamaguchi, H. Shoda, R. Ohhira, A. Noda, S. Fujita, N. Kawahara</i>	

SESSION E: ULTRA LOW NOISE RECEIVERS FOR RADIO ASTRONOMY

Receiver Integration for Mid-band Square Kilometer Array Demonstrator Applications	57
<i>S.A. Jackson, R.G. Gough, Y. Moghe</i>	
Front-end Integration Requirements for the Square Kilometre Array Radio Telescope	60
<i>J.G. Bij De Vaate, R.H. Witvers, E.E.M. Woestenburg</i>	

A Low Noise Integrated 0.3-16 GHz Differential Amplifier for Balanced Ultra Wideband Antennas	63
<i>N. Wadefalk, P. Kildal, H. Zirath</i>	
LNA Design Based on an Extracted Single Gate Finger Model	67
<i>S.J. Mahon, A. Dadello, P. Vun, J. Tarazi, A.C. Young, M.C. Heimlich, J.T. Harvey, A.E. Parker</i>	

SESSION F: III-V ADVANCED IC TECHNOLOGY

InP HBT Integrated Circuit Technology for Terahertz Frequencies	71
<i>M. Urteaga, M. Seo, J. Hacker, Z. Griffith, A. Young, R. Pierson, P. Rowell, A. Skalare, M.J.W. Rodwell</i>	
A Low 1/f Noise and High Reliability InP/GaAsSb DHB T for 76 GHz Automotive Radars	75
<i>K. Kanaya, H. Amasuga, S. Watanabe, Y. Yamamoto, N. Kosaka, S. Miyakuni, S. Goto, A. Shima</i>	
75GHz Ga₂O₃/GaN Single Nanowire Metal-Oxide-Semiconductor Field-effect Transistors	79
<i>J. Yu, Y. Wu, J. Huang, L. Peng</i>	
Development of 90nm InGaAs HEMTs and Benchmarking Logic Performance with Si CMOS	83
<i>K. Cheng, D. Chan, F. Tan, H. Xu, M. Feng</i>	

SESSION G: DIGITAL AND OPTOELECTRONIC SYSTEMS

Compacting High-end Computing Systems with Dense WDM Silicon Photonic Interconnects	87
<i>A. V. Krishnamoorthy, X. Zheng, G. Li, P. Dong, D. Feng, T. Pinguet, A. Mekis, H. Schwetman, J. Lexau, D. Patil, F. Liu, P. Koka, M. McCracken, I. Shubin, H. Thacker, Y. Luo, K. Raj, J. G. Mitchell, R. Ho, M. Asghari, J. E. Cunningham</i>	
32 GS/s Soft Decision LSI in 0.13 μm SiGe BiCMOS for Forward Error Correction in Optical Communications	90
<i>T. Kobayashi, S. Kametani, H. Tagami, K. Koguchi, T. Mizuochi</i>	
InP IC Technology Powers Agilent's Infiniium 90000 X-Series Real Time Oscilloscope	94
<i>R. Shimon, B. Asay, D. Dascher, K. Griggs, C. Rehorn, M. Adamski, E. Ehlers, C. Hutchinson, B. Doerr</i>	

SESSION H: III-V/SILICON HETEROGENEOUS INTEGRATION

High Performance Mixed Signal Circuits Enabled by the Direct Monolithic Heterogeneous Integration of InP HBT and Si CMOS on a Silicon Substrate	98
<i>T.E. Kazior, J.R. LaRoche, D. Lubyshev, J.M. Fastenau, W.K. Liu, M.T. Bulsara, E.A. Fitzgerald, M. Urteaga, J. Bergman, M.J. Choe, K.J. Lee, T. Seong, M. Seo, A. Yen, D. Smith, D. Clark, R. Thompson, C. Drazek, E. Guiot</i>	
Advanced Heterogeneous Integration of InP HBT and CMOS Si Technologies	102
<i>A. Gutierrez-Aitken, P. Chang-Chien, D. Scott, K. Hennig, E. Kaneshiro, P. Nam, N. Cohen, D. Ching, K. Thai, B. Oyama, J. Zhou, C. Geiger, B. Poust, M. Parlee, R. Sandhu, W. Phan, A. Oki, R. Kagiwada</i>	
Mixed-signal Circuits Using 250nm InP HBT Technology Integrated with 90nm CMOS	106
<i>K.R. Elliott, C. Baringer, J.C. Li, Y. Royter, P.R. Patterson, T. Hussain</i>	
Monolithically-Integrated Digital Circuits with Light Emitting Diodes in Lattice-Matched Si/III-V-N/Si Heterostructure	109
<i>A. Wakahara, K. Yamane, K. Noguchi, S. Tanaka, Y. Furukawa, H. Okada, H. Yonezu</i>	

SESSION I: HIGH SPEED & MM-WAVE CMOS

An 8.2 to 20.1 GHz LC PLL with Sub-100 fs Jitter in 0.13 μm SiGe BiCMOS	113
<i>M. Demirkan, G. Steinbach, K.A. Nishimura, J.P. Keane, B.E. Wuppermann</i>	
A CMOS Programmable Gain Amplifier with Constant Current-Density Based Transconductance Control	117
<i>S.Y. Kang, S.T. Ryu, C.S. Park</i>	
A 80-92-GHz Receiver Front-End using Slow-Wave Transmission Lines in 65nm CMOS	121
<i>C. Wang, Z. Chen, V. Jain, P. Heydari</i>	
Gbps 60GHz CMOS OOK Modulator and Demodulator	125
<i>J.J. Lee, C.W. Byeon, K.C. Eun, I.Y. Oh, C.S. Park</i>	

SESSION J: POWER AND SWITCHING GAN DEVICES

Soft Switching Controlled AlGa_N based Power Transistors for Induction Heating Applications	129
<i>Y. Niiyama, N. Ikeda, S. Kato, M. Masuda</i>	
Recent Advances in GaN Power Switching Devices	133
<i>S. Tamura, Y. Anda, M. Ishida, Y. Uemoto, T. Ueda, T. Tanaka, D. Ueda</i>	
Developing GaN HEMTs for Ka-Band with 20W	137
<i>K. Takagi, K. Matsushita, Y. Kashiwabara, K. Masuda, S. Nakanishi, H. Sakurai, K. Onodera, H. Kawasaki, Y. Takada, K. Tsuda</i>	
S-parameter Analysis of GaN Schottky Diodes for Microwave Power Rectification	141
<i>J. Ao, K. Takahashi, N. Shinohara, N. Niwa, T. Fujiwara, Y. Ohno</i>	

SESSION K: MM-WAVE OSCILLATORS AND PHASE SHIFTERS

An InP VCO with Static Frequency Divider for Millimeter Wave Clock Generation	145
<i>M. Stuenkel, M. Feng</i>	
An mHEMT Q-Band Integrated LNA and Vector Modulator MMIC	149
<i>J. Lynch, F.A. Traut, K. Benson, R. Tshudy</i>	
Design and Characterization of a V-Band Quadrature VCO based on a Common-Collector SiGe Colpitts VCO	153
<i>A. Barghouthi, A. Krause, C. Carta, F. Ellinger, C. Scheytt</i>	
Voltage-Controlled Phase Shifter in a Surface Mount Package for 40- and 100-Gb/s Optical Transceivers	156
<i>H. Nosaka, M. Nagatani, K. Sano, T. Ito, S. Tsunashima, K. Murata</i>	

SESSION L: POWER AMPLIFIERS FOR MICROWAVE AND MMW APPLICATIONS

An X-Band 50W-output/30%-PAE GaN Power Amplifier with Bandwidth/Ripple-Optimized Bandpass Impedance-Matching Networks	160
<i>H. Uchida, E. Kuwata, H. Ohtsuka, K. Yamanaka, K. Yamauchi, K. Mori, M. Nakayama, A. Inoue, Y. Hirano</i>	
Design and Performance of a High Efficiency Ka-band Power Amplifier MMIC	164
<i>C.F. Campbell, D.C. Dumka, M. Kao, D.M. Fanning</i>	
Scaling of InP HEMT Cascode Integrated Circuits to THz Frequencies	168
<i>W.R. Deal, K. Leong, X.B. Mei, S. Sarkozy, V. Radisic, J. Lee, P.H. Liu, W. Yoshida, J. Zhou, M. Lange</i>	
E-band 85-mW Oscillator and 1.3-W Amplifier ICs using 0.12-μm GaN HEMTs for Millimeter-wave Transceivers	172
<i>Y. Nakasha, S. Masuda, K. Makiyama, T. Ohki, M. Kanamura, N. Okamoto, T. Tajima, T. Seino, H. Shigematsu, K. Imanishi, T. Kikkawa, K. Joshin, N. Hara</i>	

SESSION M: GAN AND GAAS HFETS

Single-Polarity Power Supply Bootstrapped Comparator for GaN Smart Power Technology	176
<i>X. Liu, K.J. Chen</i>	
Comparative Study of AlGa_N/Ga_N HEMTs on Free-Standing Diamond and Silicon Substrates for Thermal Effects	180
<i>M. Trejo, K.D. Chabak, B. Poling, R. Gilbert, A. Crespo, J.K. Gillespie, M. Kossler, D.E. Walker, G.D. Via, G.H. Jessen, D. Francis, F. Faili, D. Babic, F. Ejeckam</i>	
Advanced Full Periphery pHEMT Switch with Optimum Figure of Merit Ron^*Coff	184
<i>C. Yuan, S.M.J. Liu, S. Takatani, J. Sun</i>	
Development of Ka-band GaAs pHEMTs with Output Power Over 1 W/mm	188
<i>D.C. Dumka, M. Kao, E. Beam, T. Chou, H. Tserng, D.M. Fanning</i>	

SESSION N: MM-WAVE TO THZ MIXING TECHNOLOGIES

Packaged, Integrated 32 to 40 GHz Millimetre-Wave Up-Converter	192
<i>E.R.O. Convert, A.P. Fattorini, S.J. Mahon, P.W. Evans, M.G. McCulloch, S. Hwang, R.G. Mould, A.C. Young, J.T. Harvey</i>	
Subharmonically Pumped 210 GHz I/Q Mixers	196
<i>D. Lopez-Diaz, I. Kalfass, A. Tessmann, A. Leuther, H. Massler, M. Schlechtweg, O. Ambacher</i>	

A Fundamental Upconverting Gilbert Mixer for 100 GHz Wireless Applications	200
<i>M. Gavell, M. Fernsdahl, H. Zirath, M. Urteaga, R. Pierson</i>	

SESSION O: LATE NEWS PAPERS

RF Receiver Front End for 868.6-MHz Band IEEE 802.15.4 PSSS Standard.....	204
<i>M. Anis, G. Grau, A. Wolf, R. Kraemer</i>	
A 0.1–1.8 GHz, 100 W GaN HEMT Power Amplifier Module	208
<i>K. Krishnamurthy, D. Lieu, R. Vetury, J. Martin</i>	
A Metamorphic HEMT S-MMIC Amplifier with 16.1 dB Gain at 460 GHz.....	212
<i>A. Tessmann, A. Leuther, R. Loesch, M. Seelmann-Eggebert, H. Massler</i>	

SESSION P: LATE NEWS PAPERS

A 56 Gbit/s 0.35 μm SiGe Limiting Amplifier with 2.4 THz Gain-Bandwidth-Product	216
<i>M. Grozing, M. Schmidt, M. Berroth</i>	
A 2.4 V_{pp}, 60-Gb/s, mm-Wave DAC-based CMOS Driver with Adjustable Amplitude and Peaking Frequency	220
<i>R.A. Aroca, P. Schvan, S.P. Voinigescu</i>	
An Ultrahigh-Speed Low-Power DAC using InP HBTs for Multi-Level Optical Transmission Systems	224
<i>M. Nagatani, H. Nosaka, S. Yamanaka, K. Sano, K. Murata</i>	
Author Index	